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|--------------|----------|---|
| <b>SANYO</b> | No.5122A | <b>DD54SC</b>   |
|              |          | Silicon Diffused Junction Type<br><b>Damper Diode for Ultrahigh-Definition Display Applications</b> |

**Features**

- High breakdown voltage ( $V_{RRM} : 1600V$ ).
- High reliability.
- One-point fixing type plastic molded package facilitating easy mounting and heat dissipation.
- Fast forward/reverse recovery time.

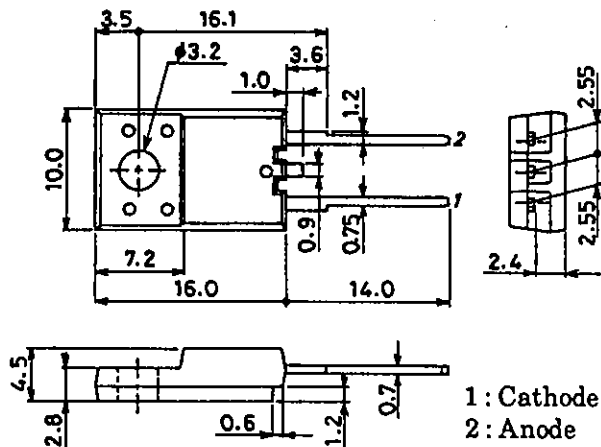
**Absolute Maximum Ratings at  $T_a = 25^\circ C$**

|                                     |           |   | unit       |
|-------------------------------------|-----------|---|------------|
| Repetitive Peak Reverse Voltage     | $V_{RRM}$ | 1600                                      | V          |
| Non-repetitive Peak Reverse Voltage | $V_{RSM}$ | 1600                                      | V          |
| Average Output Current              | $I_o$     | 5   | A          |
| Peak Output Current                 | $I_{op}$  | $PW \leq 100\mu s, \text{duty} \leq 50\%$ | 20 A       |
| Surge Forward Current               | $I_{FSM}$ | Sine wave, 10ms                           | 50 A       |
| Junction Temperature                | $T_j$     | 150                                       | $^\circ C$ |
| Storage Temperature                 | $T_{stg}$ | -55 to +150                               | $^\circ C$ |

**Electrical Characteristics at  $T_a = 25^\circ C$**

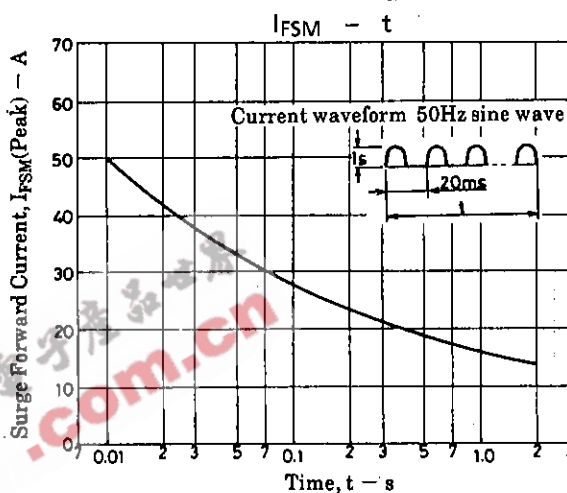
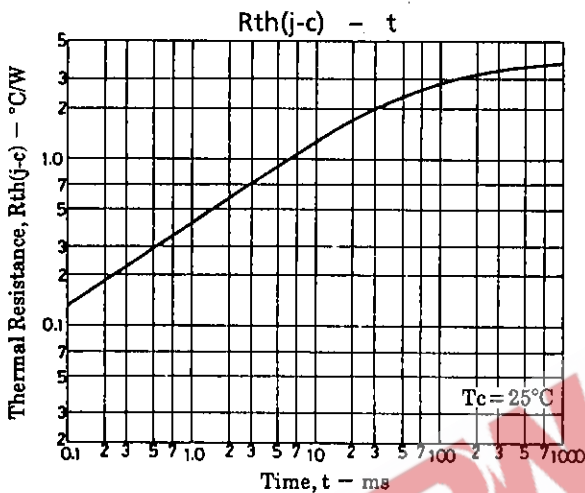
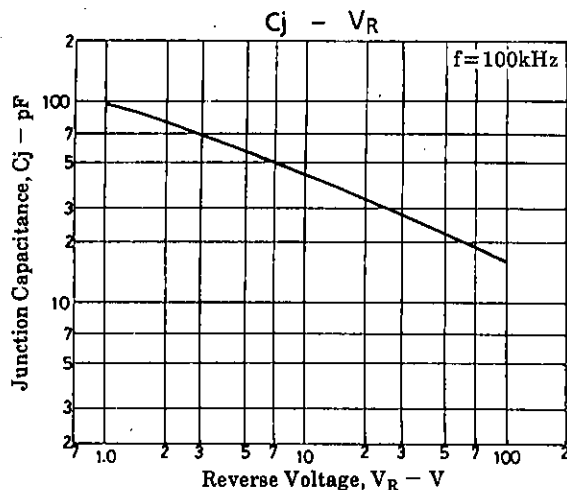
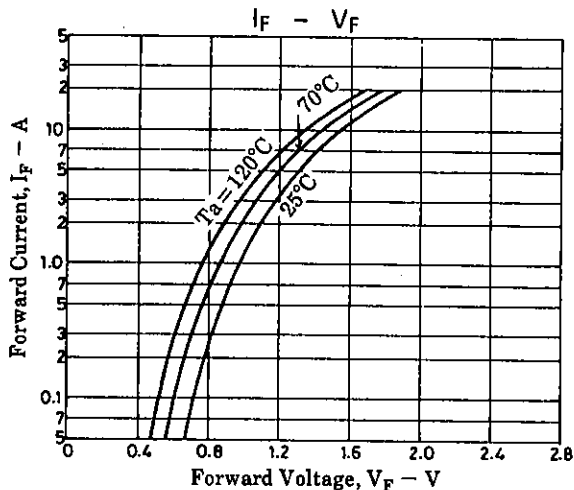
|                       |               |                            | min  | typ  | max | unit         |
|-----------------------|---------------|----------------------------|------|------|-----|--------------|
| Reverse Voltage       | $V_R$         | $I_R = 1mA$                | 1600 |      |     | V            |
| Forward Voltage       | $V_F$         | $I_F = 5A$                 |      | 1.8  |     | V            |
| Reverse Current       | $I_R$         | $V_R = 1000V$              |      | 200  |     | $\mu A$      |
| Reverse Recovery Time | $t_{rr}$      | $I_F = 100mA, I_R = 100mA$ |      | 1.5  |     | $\mu s$      |
| Forward Recovery Time | $t_{fr}$      | $I_F = 100mA$              | 0.1  | 0.2  |     | $\mu s$      |
| Junction Capacitance  | $C_j$         | $V_R = 10V, f = 100kHz$    | 40   |      |     | pF           |
| Thermal Resistance    | $R_{th(j-c)}$ | Junction - Case            |      | 3.75 |     | $^\circ C/W$ |

**Package Dimensions 1253**  
(unit : mm)



SANYO : TO-220FI(LS)-SB

DD54SC



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